

NATIONAL UNIVERSITY OF SINGAPORE

PC3235 – Solid State Physics I

(Semester I: AY 2017-18)

Time Allowed: 2 Hours

Instructions to candidates

1. Write your student ID on **both** this exam paper (below) **and** the answer books. **Do not write your name.**
2. This exam paper comprises **six (6)** printed pages (including this one).
3. Answer **all** the **sixteen (16)** questions for **Part I directly on the test paper.**
4. Answer **all** the **three (3)** problems in **Part II only in the answer books.** In this part, either show your calculations or justify adequately. Please start each problem in a new page.
5. **At the end, you should submit both your exam paper and answer book.**
6. This is a **closed book** examination with authorized materials. Students are allowed to use an A4-sized sheet (both sides) of self-manuscript notes.
7. You can use a non-programmable scientific calculator, but no other electronic devices.

Student ID

Physical constants and units (SI)

m_e	$9.109 \times 10^{-31} \text{ kg}$	k_B	$1.381 \times 10^{-23} \text{ kg} \cdot \text{m}^2 \cdot \text{s}^{-2} \cdot \text{K}^{-1}$
e	$1.602 \times 10^{-19} \text{ A} \cdot \text{s}$	\hbar	$1.054 \times 10^{-34} \text{ kg} \cdot \text{m}^2 \cdot \text{s}^{-1}$
N_A	$6.022 \times 10^{23} \text{ mol}^{-1}$	c	$2.998 \times 10^8 \text{ m} \cdot \text{s}^{-1}$

$$1 \text{ eV} \simeq 1.602 \times 10^{-19} \text{ Joule} \simeq 1.160 \times 10^4 \text{ Kelvin}$$

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Part I (40 %, 2.5 % each)

(circle or write your answers directly here in the exam paper)

- How many lattice points (or atoms) are contained in the FCC *conventional* unit cell?
A one B two C three D four
- If the inter-ionic distance in a NaCl crystal is 0.28 nm, the *primitive lattice parameter* is
A 0.14 nm B 0.56 nm C 0.07 nm D 0.40 nm
- What are the relations among the lattice constants a, b, c , as well as among the angles α, β, γ between the primitive directions in a *tetragonal* Bravais lattice?
A $\begin{cases} a=b=c \\ \alpha=\beta=\gamma=90 \end{cases}$ B $\begin{cases} a=b \neq c \\ \alpha=\beta=\gamma=90 \end{cases}$ C $\begin{cases} a \neq b \neq c \\ \alpha=\beta=\gamma=90 \end{cases}$ D $\begin{cases} a \neq b \neq c \\ \alpha \neq \beta = \gamma = 90 \end{cases}$
- If the volume of the primitive cell in a three-dimensional crystal structure is V_c , the volume of its primitive reciprocal cell is
A $2\pi/V_c$ B $(2\pi)^3 V_c$ C $2\pi V_c$ D $(2\pi)^3/V_c$
- If q, μ and n represent the charge, mobility and concentration of carriers in a metal, its Drude conductivity is
A $\sigma = n/\mu q$ B $\sigma = \mu q/n$ C $\sigma = nq/\mu$ D $\sigma = \mu q n$
- In a Hall effect measurement where a transverse (Hall) field E_y develops under a longitudinal current density J_x and constant magnetic field B_z , the Hall constant is given by
A $\frac{E_y}{J_x B_z}$ B $\frac{J_x}{E_y B_z}$ C $\frac{B_z E_y}{J_x}$ D $\frac{B_z J_x}{E_y}$
- Near room temperatures, the Drude relaxation time in a metal depends on temperature as
A $\tau \propto T$ B $\tau \propto 1/T$ C $\tau = \text{constant}$ D $\tau = 0$
- At a given temperature, the electron density in silver is $5.86 \times 10^{23} \text{ cm}^{-3}$ and its resistivity is $1.51 \mu\Omega \cdot \text{cm}$. What is the Drude relaxation time, in seconds?
Your response: _____
- If the Debye temperature of a crystal is $\Theta_D = 400 \text{ K}$, what is the corresponding Debye frequency, in rad/s?
Your response: _____

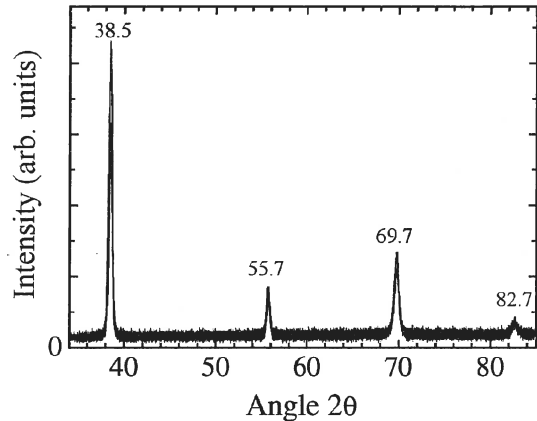
10. Very close to $T = 0$, the specific heat of a *metallic crystal* varies with temperature as
- A $\propto T^3$ B $\propto T$ C $\propto e^{T/\Theta_D}$ D $\propto e^{-T/\Theta_D}$
11. If \mathbf{G} represents any reciprocal lattice vector of a crystal whose periodic potential is weak, one expects the appearance of gaps in the electronic energy dispersion *every time* the electron's wavevector \mathbf{k} satisfies
- A $|\mathbf{k}| \ll |\mathbf{G}|$ B $\mathbf{k} \cdot \mathbf{G} = 0$ C $|\mathbf{k}| = |\mathbf{k} \pm \mathbf{G}|$ D \mathbf{k} is parallel to \mathbf{G}
12. The velocity of a Bloch electron belonging to the energy band $\varepsilon_n(\mathbf{k})$ is defined as
- A $\hbar^{-1} \nabla_{\mathbf{k}} \varepsilon_n(\mathbf{k})$ B $\hbar \mathbf{k} / m$ C $\sqrt{2\varepsilon_n(\mathbf{k})/m}$ D $\hbar d\mathbf{k}/dt$
13. In order for a crystalline solid to be an insulator, it is *necessary* that the number of electrons per unit cell be
- A zero B an odd number C an even number D less than 2
14. The density of electrons in the conduction band of an *intrinsic* semiconductor with band gap E_g varies with temperature as
- A $\propto e^{E_g/2k_B T}$ B $\propto e^{-E_g/2k_B T}$ C $\propto E_g/k_B T$ D $\propto (E_g/k_B T)^2$
15. In the context of a tight-binding description of the electronic band structure, if the lattice constant is increased, one expects the width of the electronic energy bands to
- A decrease B remain the same C increase
16. In comparison with a partially filled band, the current carried by electrons in a completely filled band is
- A the same B larger C zero

Part II (60 %)
(write your solutions only in the answer book)

Problem 1 20% [3, 8, 5, 4]

An X-ray diffraction experiment using monochromatic light of wavelength $\lambda = 0.154 \text{ nm}$ was performed on the powder of a crystal whose exterior aspect reveals a *cubic* symmetry. The scattered intensity spectrum obtained as a function of *scattering angle* is plotted in the figure beside, and shows the lowest Bragg peaks recorded at

$$2\theta = \{38.5^\circ, 55.7^\circ, 69.7^\circ, 82.7^\circ\}.$$

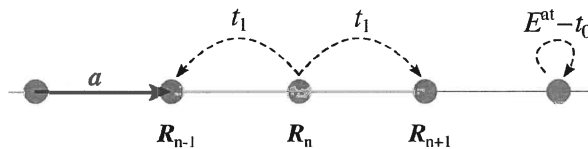


This substance is known to be monoatomic.

- State (or calculate) the lattice structure factors of the body-centred (BCC) and face-centred (FCC) lattices when these are described in terms of conventional cubic unit cells.
- Determine whether this crystal has a BCC or a FCC lattice (show your work).
- Determine the lattice parameter, a , of its *conventional* cubic cell.
- Determine the volume of the 1st Brillouin zone associated with the crystal's Bravais lattice as a function of the parameter a . [*hint: the crystal is not simple cubic, but you can obtain the result directly from the conventional cubic unit cell*]

Problem 2 15% [6, 5, 4]

Consider the tight-binding description of a perfect one-dimensional, monoatomic crystal. It is known that only one band crosses the Fermi energy, ε_F , and that band arises from contributions of a *single* atomic orbital at each unit cell, $\phi(r)$.



- Defining the matrix elements of the Hamiltonian of an electron in the periodic potential as (the hopping amplitudes illustrated in the figure)

$$E^{at} - t_0 \equiv \langle \phi(0) | \hat{H} | \phi(0) \rangle, \quad -t_1 \equiv \langle \phi(a) | \hat{H} | \phi(\pm a) \rangle, \quad (t_1 > 0)$$

obtain the analytical expression for the electronic band dispersion, $\varepsilon(k)$, in the nearest-neighbour, orthogonal tight-binding approximation.

- Determine ε_F when the number of electrons in this band amounts to 1 per unit cell.
- For such value of ε_F , is this an electrical conductor or an insulator? Justify.

Problem 3 25 % [3, 4, 6, 8, 4]

Consider the description of *free* electrons in a piece of metal with volume V according to Sommerfeld's theory (in 3 dimensions).

- a) Derive the density of electronic states per spin (DOS), $g(\varepsilon)$, for free electrons.
- b) State how the volume density of electrons, n_e , is related to the DOS. Hence, or otherwise, obtain the Fermi energy, ε_F , as a function of n_e .
- c) If the electronic density is kept constant, derive how the chemical potential, μ , deviates from ε_F as a function of temperature, to lowest order in temperature. Express your result in terms of the DOS. [*hint: use Sommerfeld's expansion; also, it's better to keep $g(\varepsilon)$ unspecified throughout your steps and final result*]
- d) The thermal conductivity, κ , relates the heat flux that results from a temperature gradient through $\mathbf{J}^q = -\kappa \nabla T$. It can be calculated within Drude-Sommerfeld theory from

$$\kappa = \frac{2\tau}{3Vm} \frac{\partial}{\partial T} \sum_{\mathbf{k}} \varepsilon_{\mathbf{k}}^2 f(\varepsilon_{\mathbf{k}}),$$

where τ is the relaxation time (assumed to be \mathbf{k} -independent), $\varepsilon_{\mathbf{k}}$ the free electron energy dispersion, m the electron's mass, and $f(\varepsilon)$ represents the Fermi-Dirac distribution. Show that, to lowest order in a Sommerfeld expansion, the above expression leads to

$$\kappa \simeq \frac{\pi^2 n_e \tau k_B^2 T}{3m}.$$

[*hint: you will need the result of question c; also, do $\partial/\partial T$ only at the end*]

- e) Compute κ at $T = 300\text{ K}$ for a metal whose Drude resistivity is $1.7\ \mu\Omega \cdot \text{cm}$ at that temperature. Present the magnitude of your final result in SI units.

Note: recall that the lowest orders of the Sommerfeld expansion are

$$\int_{-\infty}^{+\infty} H(\varepsilon) f(\varepsilon) d\varepsilon = \int_{-\infty}^{\mu} H(\varepsilon) d\varepsilon + \frac{\pi^2}{6} (k_B T)^2 H'(\mu) + \frac{7\pi^4}{360} (k_B T)^4 H'''(\mu) + \mathcal{O}(T^6).$$

— end of exam paper (VMP)